

PSMN1R9-80SSE

N-channel 80 V, 1.9 mOhm MOSFET with enhanced SOA in I FPAK88

1 November 2021

Preliminary data sheet

1. General description

N-channel enhancement mode MOSFET in a LFPAK88 package qualified to 175 °C. Part of Nexperia's "ASFETs for hotswap" portfolio, the PSMN1R9-80SSE delivers very low R_{DSon} and a very strong linear-mode (SOA) performance in a high-reliability copper-clip LFPAK88 package.

PSMN1R9-80SSE complements the latest "hot-swap" controllers – robust enough to withstand substantial inrush currents during turn-on, low R_{DSon} to minimize I^2R losses and deliver optimum efficiency when turned fully ON.

2. Features and benefits

- Fully optimized Safe Operating Area (SOA) for superior linear mode operation
- Low R_{DSon} for low I²R conduction losses
- LFPAK88 package for applications that demand the highest performance and reliability

3. Applications

- Hot swap
- · Load switch
- Soft start
- E-fuse
- Telecommunication and computing systems based on a 48 V backplane/supply rail

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	80	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	286	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	340	W
Tj	junction temperature			-55	-	175	°C
Static chara	cteristics			'	'		'
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 12		-	1.6	1.9	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 100 °C; Fig. 13		-	2.6	3	mΩ
Dynamic ch	aracteristics			'	'		1
Q _{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 40 V; V _{GS} = 10 V;		7	23	53	nC
Q _{G(tot)}	total gate charge	T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>		77	155	232	nC
Avalanche r	ruggedness						·
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 90 A; V_{sup} ≤ 80 V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 179 µs; $Fig. 4$	[1]	-	-	840	mJ



Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Source-drain d	Source-drain diode						
Q _r		$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V}; V_{DS} = 40 \text{ V}; T_j = 25 °C; Fig. 18$	[2]	-	60	-	nC

- [1] Protected by 100% test
- [2] includes capacitive recovery

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	S	source		D
3	S	source		
4	S	source		G_(↓ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □
mb	D	mounting base; connected to drain	LFPAK88 (SOT1235)	mbb076 S

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PSMN1R9-80SSE	LFPAK88	plastic, single-ended surface-mounted package (LFPAK88); 4 leads; 2 mm pitch; 8 mm x 8 mm x 1.6 mm body	SOT1235		

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN1R9-80SSE	X1E9S80S

2/13

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	80	V
V_{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 175 °C; R_{GS} = 20 kΩ		-	80	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	340	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>		-	286	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	202	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3		-	1142	Α
T _{stg}	storage temperature			-55	175	°C
T _j	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
Source-drain di	ode					
Is	source current	T _{mb} = 25 °C		-	286	Α
I _{SM}	peak source current	pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C		-	1142	Α
Avalanche rugg	edness			'	•	
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	I_D = 90 A; $V_{sup} \le 80$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 179 μs; Fig. 4	[1]	-	840	mJ
I _{AS}	non-repetitive avalanche current	V_{sup} = 80 V; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; R_{GS} = 50 Ω ; $Fig. 4$	[1]	-	90	A

[1] Protected by 100% test

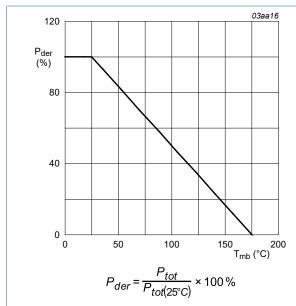


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

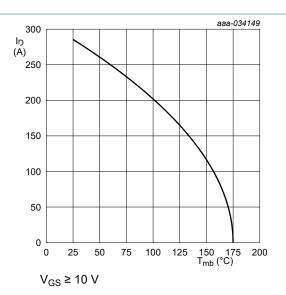
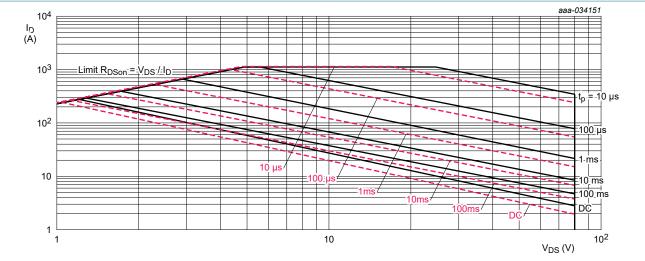
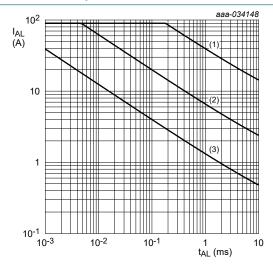


Fig. 2. Continuous drain current as a function of mounting base temperature



 T_{mb} = 25 °C; I_{DM} is a single pulse

Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage



(1) $T_{j \text{ (init)}}$ = 25 °C; (2) $T_{j \text{ (init)}}$ = 150 °C; (3) Repetitive Avalanche

Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	0.2	0.44	K/W
R _{th(j-a)}	thermal resistance from	Fig. 6	-	35	-	K/W
juncti	junction to ambient	Fig. 7	-	70	-	K/W

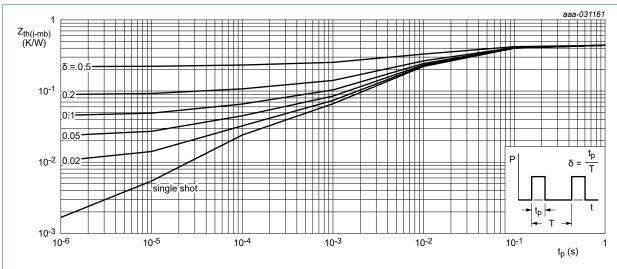


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

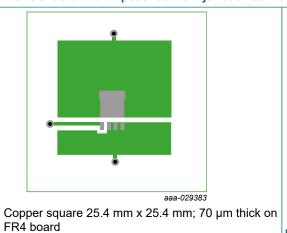
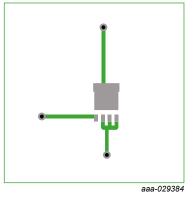


Fig. 6. PCB layout for resistance from junction to ambient



70 µm thick copper on FR4 board

Fig. 7. PCB layout with minimum footprint for thermal resistance from junction to ambient

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	80	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	72	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}; Fig. 11$	2	2.6	3.6	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C}$	-	1.6	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}$	-	3	-	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-6.4	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 80 V; V _{GS} = 0 V; T _j = 25 °C	-	0.02	1	μΑ
		V _{DS} = 16 V; V _{GS} = 0 V; T _j = 125 °C	-	3	100	μA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 12	-	1.6	1.9	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 100 °C; Fig. 13	-	2.6	3	mΩ
		$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 175 °C;$ Fig. 13	-	-	4.2	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	0.6	1.2	2.4	Ω
Dynamic cha	racteristics					1
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 40 V; V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	77	155	232	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	83	-	nC
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 40 V; V _{GS} = 10 V;	36	60	84	nC
Q _{GS(th)}	pre-threshold gate- source charge	T _j = 25 °C; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	34	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	26	-	nC
Q_{GD}	gate-drain charge		7	23	53	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 40 V; T _j = 25 °C; Fig. 14; Fig. 15	-	5.2	-	V
C _{iss}	input capacitance	V _{DS} = 40 V; V _{GS} = 0 V; f = 1 MHz;	7340	12235	17140	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 16</u>	1710	2843	4560	pF
C _{rss}	reverse transfer capacitance		7	64	169	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 40 \text{ V}; R_L = 1.6 \Omega; V_{GS} = 10 \text{ V};$	-	46	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	42	-	ns
t _{d(off)}	turn-off delay time	1	-	79	-	ns
t _f	fall time	1 –	-	46	-	ns
Source-drain	diode			<u> </u>	1	
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _i = 25 °C; <u>Fig. 17</u>	-	0.78	1	V

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
t _{rr}		$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$		-	54	-	ns
Q _r	recovered charge	V _{DS} = 40 V; T _j = 25 °C; <u>Fig. 18</u>	[1]	-	60	-	nC

[1] includes capacitive recovery

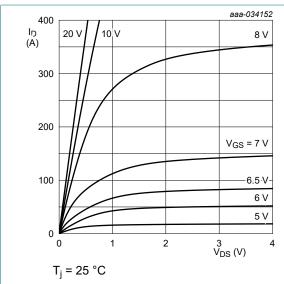


Fig. 8. Output characteristics; drain current as a function of drain-source voltage; typical values

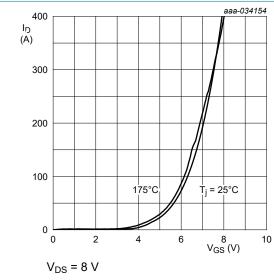


Fig. 10. Transfer characteristics; drain current as a function of gate-source voltage; typical values

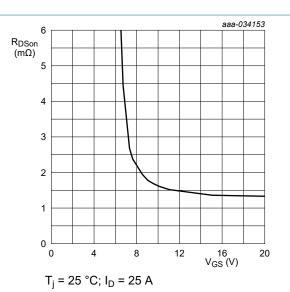


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

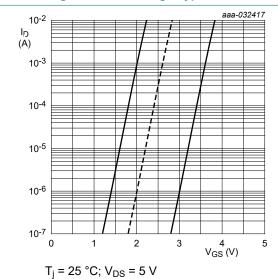


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

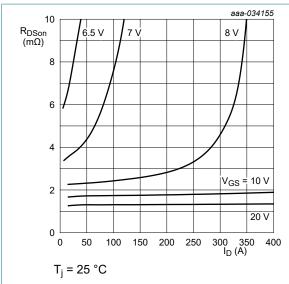


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

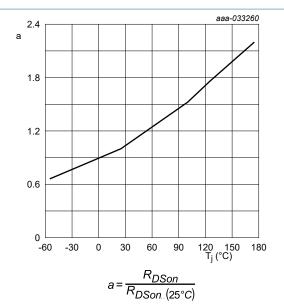


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

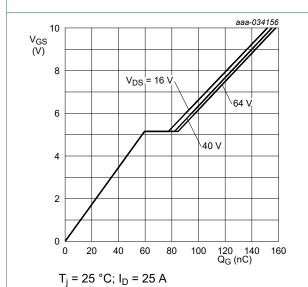


Fig. 14. Gate-source voltage as a function of gate charge; typical values

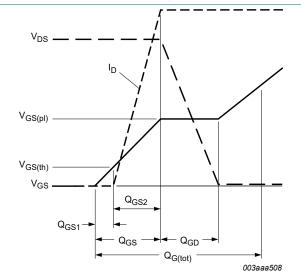
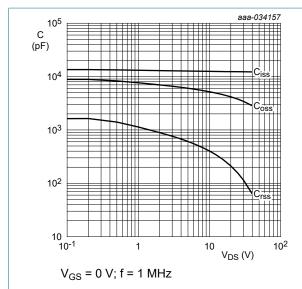


Fig. 15. Gate charge waveform definitions



as a function of drain-source voltage; typical values

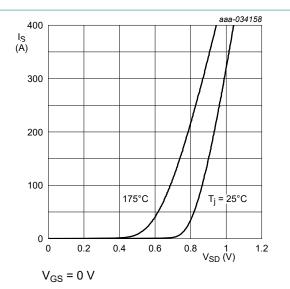


Fig. 16. Input, output and reverse transfer capacitances | Fig. 17. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

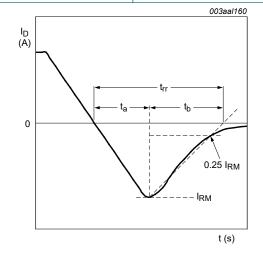


Fig. 18. Reverse recovery timing definition

11. Package outline

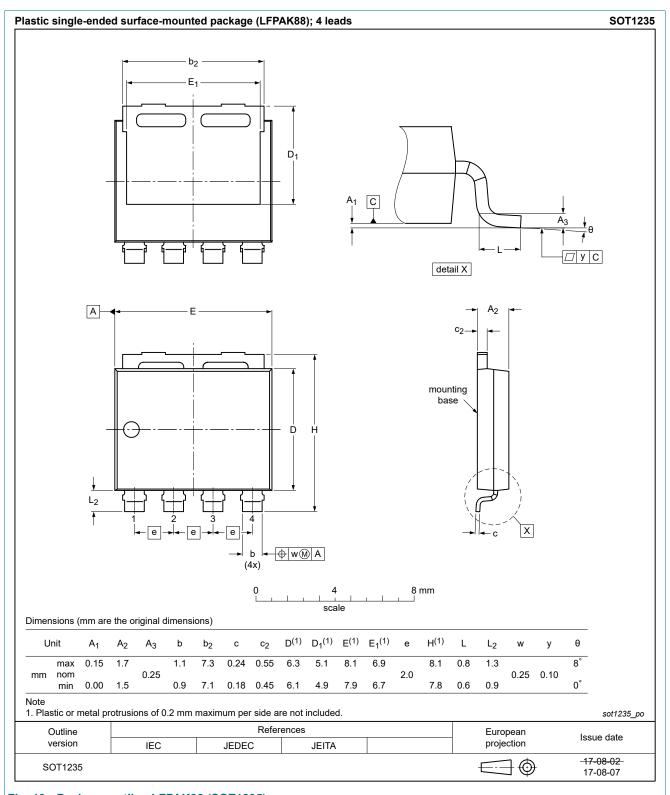
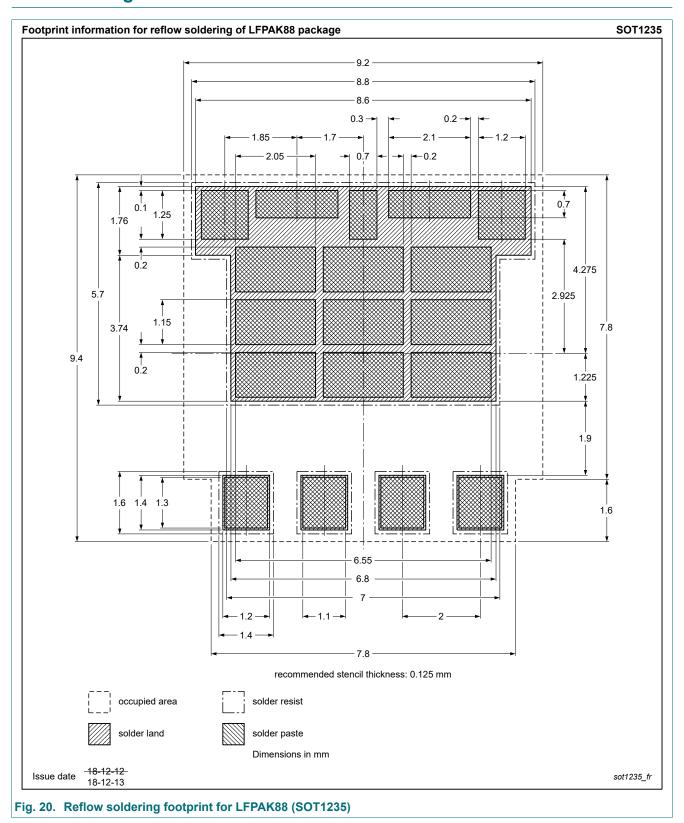


Fig. 19. Package outline LFPAK88 (SOT1235)

12. Soldering



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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